

International  
**IR** Rectifier

**IRUH33P253B1M**

**Total Ionizing Dose Test Report**

**September 2005**

Revision 1

International Rectifier currently does not have a DSAC approved Radiation Hardness Assurance Program for  
MIL-PRF-38534.

List of devices covered by this report include:

IRUH33P183B1MP  
IRUH33P183B1MK  
IRUH33P183A1MP  
IRUH33P183A1MK  
IRUH33P253B1MP  
IRUH33P253B1MK  
IRUH33P253A1MP  
IRUH33P253A1MK  
IRUH33PA13B1MP  
IRUH33PA13B1MK  
IRUH33PA13A1MP  
IRUH33PA13A1MK  
IRUH50PA23B1MP  
IRUH50PA23B1MK  
IRUH50PA23A1MP  
IRUH50PA23A1MK  
IRUH50P253B1MP  
IRUH50P253B1MK  
IRUH50P253A1MP  
IRUH50P253A1MK  
IRUH50P333B1MP  
IRUH50P333B1MK  
IRUH50P333A1MP  
IRUH50P333A1MK

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## **INTRODUCTION**

This test report covers the total ionizing dose tests performed on the IRUH33P253B1M Ultra Low Dropout linear regulator in a hermetic package. The total ionizing dose test was performed on ten samples of the device from production lot 318855, which had completed MIL-PRF-38534 "K" level assembly, screening and Group A testing May 20, 2004. On September 2<sup>nd</sup>, 2005 International Rectifier tested this device for total ionizing dose hardness at the University of Massachusetts, Nuclear Research Facility using their CO<sup>60</sup> source.

## **SUMMARY OF RESULTS**

All of the test samples passed the post radiation test requirements for total ionizing dose levels up to 750K RAD(Si). The results show a significant degradation in the "OFF" biased samples above 750K RAD(Si) but the devices all passed the post radiation test requirements after a 168hr room temperature anneal. The "ON" biased samples passed the post radiation test requirements for all of the required dose levels.

## **TEST METHOD**

The test method used as a guide in the development of the Test Plan was MIL-STD-883, Method 1019 Ionizing Radiation, Condition A. This method establishes the basic requirements for the performance and execution of the tests.

## **TEST PLAN**

The samples were exposed to CO<sup>60</sup> irradiation in both an "ON" and "OFF" biased state per the requirements of the test plan and the radiation test specification. Post radiation testing of the devices occurred at the UMass facility after each dose step was complete. The devices were tested on September 2<sup>nd</sup>, 2005 for post radiation effects for dose levels up to 1M Rad(Si). The devices were then placed on an extended room temperature anneal for 168hrs.

ON Biased serial numbers: 1677, 1678, 1689, 1693, and 1771

OFF Biased serial numbers: 1676, 1683, 1749, 1759, and 1762

Control Samples: 1703 and 1730. 1703 used for this test.

The Radiation Test Specification is included in Appendix B. The testing occurred in the following manner:

### **1.0 Purpose**

The purpose of this test is to characterize and qualify the Total Ionizing Dose effects for International Rectifier's hybrid ultra low dropout regulator devices. The data resulting from the tests may be incorporated in the IR data sheet for the product.

### **2.0 Test Responsibility**

International Rectifier shall be responsible for conducting the tests, which shall be performed at the University of Massachusetts Research Reactor facility. International Rectifier shall be responsible for the final Test Report.

### **3.0 Test Facility**

#### **3.1 Nuclear Reactor**

The University of Massachusetts Research Reactor shall be used to provide the source for Gamma radiation. UMRR will also provide information on dose rate, total dose, irradiation test times and dosimetry for this evaluation.

#### **3.2 Test Equipment**

The necessary test equipment including interface board, cables, power supplies, measurement system, etc. shall be provided by International Rectifier.

#### **3.3 Sample Size**

Sample size shall be determined based on device type, characterization parameters. As a minimum, the sample size shall meet the requirements of Mil- PRF-38534. Sample size for this TID evaluation equals 12 devices. Five of the samples shall be biased with the worst-case input voltage of 6.8 volts and five samples shall be biased "in-circuit" with the power supply turned off. Two samples shall be maintained as controls of which one shall be tested at each dose step.

### **4.0 Test Devices**

#### **4.1 The following device is planned for Total Ionizing Dose characterization:**

- a. IRUH33P253B1M

**4.2 All devices shall be subjected to a minimum 168hrs of burn-in and verified for correct electrical performance prior to arrival at UMRR.**

**4.3 All devices shall be tested after each radiation exposure per T090067G within 1 hour and placed back on to radiation exposure within 2 hours.**

### **5.0 Test Method**

MIL-STD-883, Method 1019 Condition A shall be used to establish the procedure for all testing described herein.

### **6.0 Record Keeping**

The Reactor facility shall provide dosimetry data for the CO<sup>60</sup> source. Each exposure run shall be cataloged with the appropriate number in order to maintain correlation to the appropriate data set. IR will be responsible for collecting and compiling the test data.

### **7.0 Test Report**

The Test Report shall include the following information:

- a. Device type(s), serial numbers, wafer lot identification (per active component)
- b. Test dates
- c. Facility, source type
- d. Bias conditions
- e. Comments and observations
- f. Pre and Post Electrical data
- g. Summary descriptive including graphs

## **TEST FACILITY**

The University of Massachusetts, Lowell, Nuclear Research Reactor is a 1 Mega-Watt, Uranium<sup>235</sup> enhanced core reactor. The UMass Lowell Radiation Laboratory provides controlled radiation environments and analytical measurement services to government organizations and industry. The laboratory provides facilities for proton, neutron, and gamma environments. The Gamma Cave is an irradiation room inside this facility having an equi-dimensional volume of 512 cubic feet. A wide range of dose rates, 1Gray (100 rad) per hour to 10,000 Gray (1M Rad) per hour, is available. Several small ports penetrate one shielding wall to provide access for instrumentation cables.

## **Test Results**

The key pre and post radiation test results are shown graphically in Figures 1 thru 14. The raw test data for all the parameters tested is shown in Appendix A. As outlined in the Test Plan, five of the devices exposed to total ionizing dose irradiation were biased "ON" with the maximum input voltage and five samples were placed in the bias circuit with the power supply off or biased "OFF". All of the "ON" bias samples passed the post radiation test requirements up to 1M Rad (Si). The "OFF" bias samples passed the post radiation test requirements up to 750K Rad (Si) and failed for Output Voltage at 1M Rad (Si). However, these samples all recovered after the extended room temperature anneal and passed all of the post radiation test requirements. The parameters affected the most by the ionizing radiation were Output Voltage, Ripple Rejection, and Shutdown Threshold Voltage with the worst-case condition being the "OFF" bias.

### **Output Voltage – Figures 1 thru 10**

The "ON" bias sample shows a worst-case shift in output voltage of +3.8% at 500K Rad (Si) but it recovers by 1.0% at 1M Rad (Si). The "OFF" bias samples show an output voltage shift as much as +4.8% at 750K Rad (Si) and drop out of regulation at 1M Rad (Si). The shifts are most pronounced with the minimum load of 50mA.

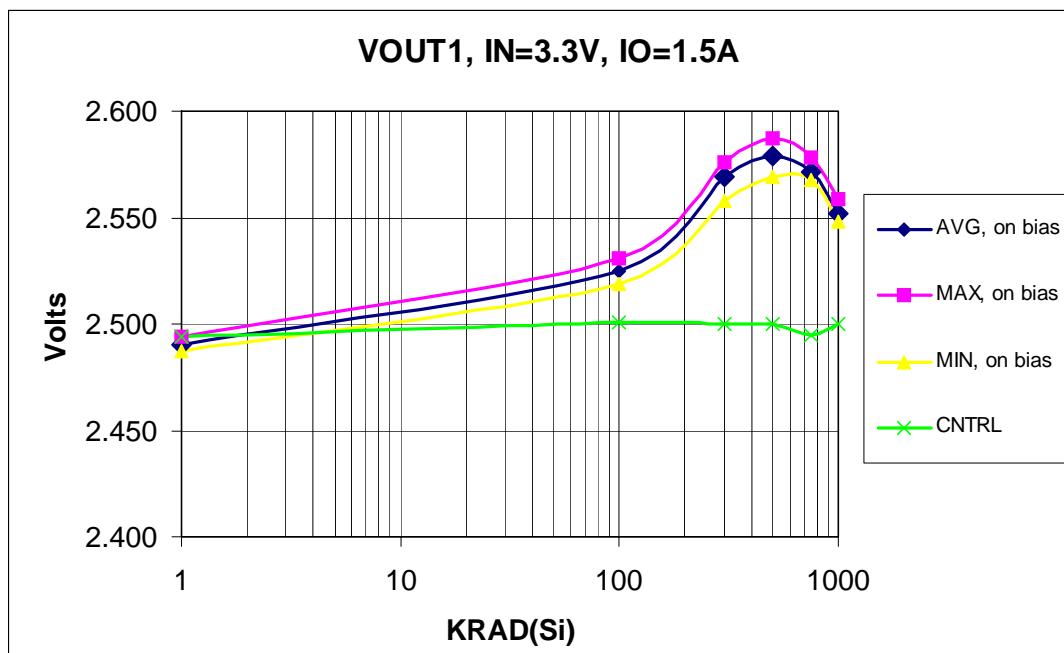


Figure 1 "ON" Biased Samples, VOUT1

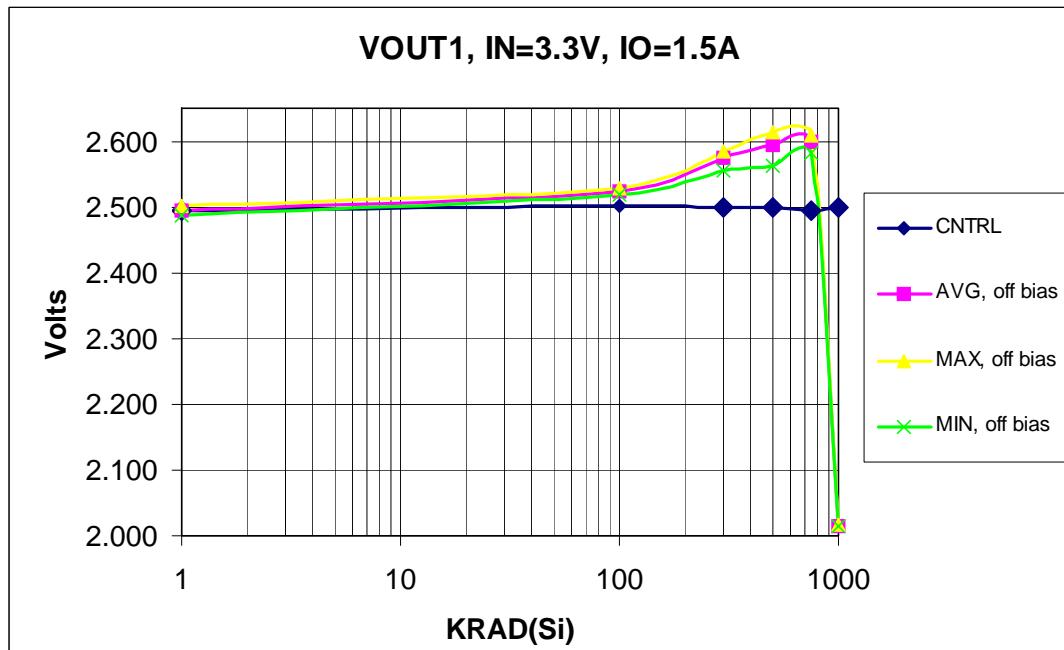


Figure 2 "OFF" Biased Samples, VOUT1

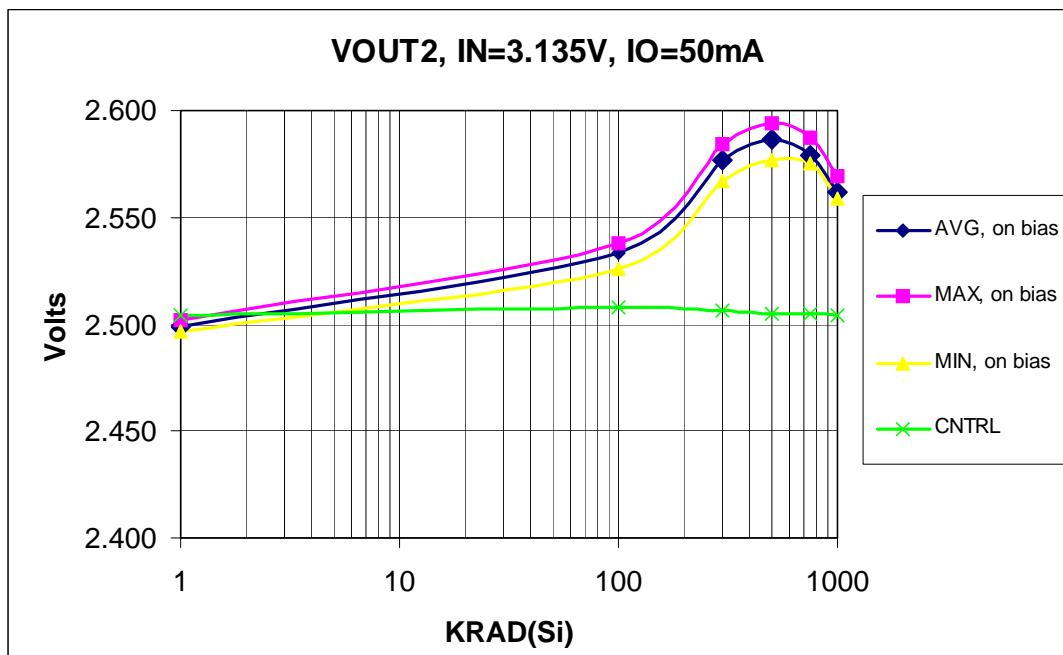


Figure 3 "ON" Biased Samples, VOUT2

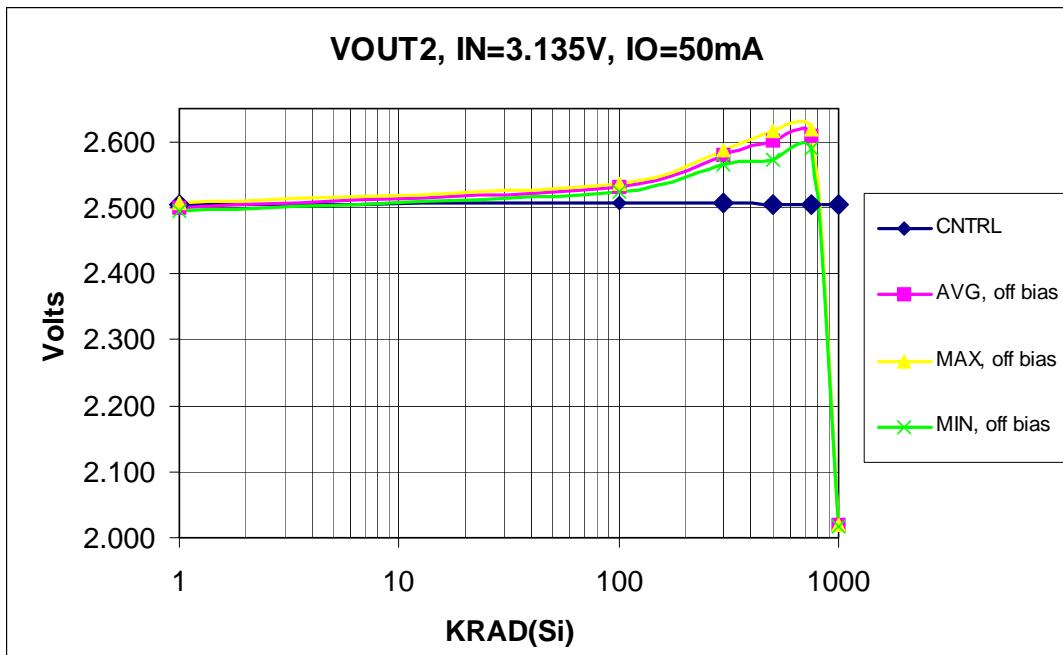


Figure 4 "OFF" Biased Samples, VOUT2

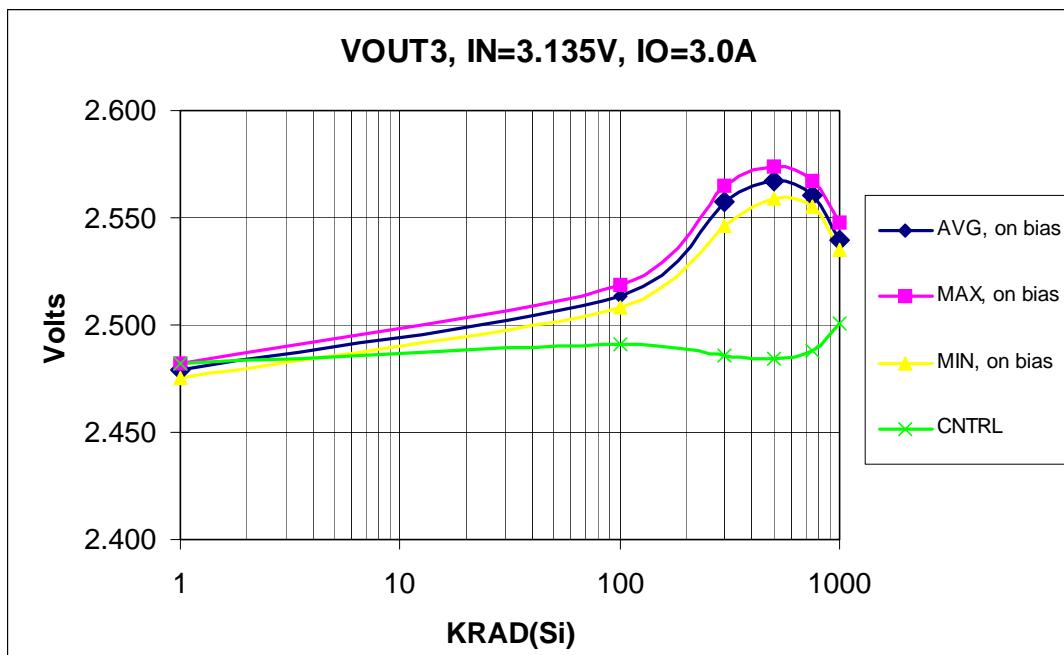


Figure 5 "ON" Biased Samples, VOUT3

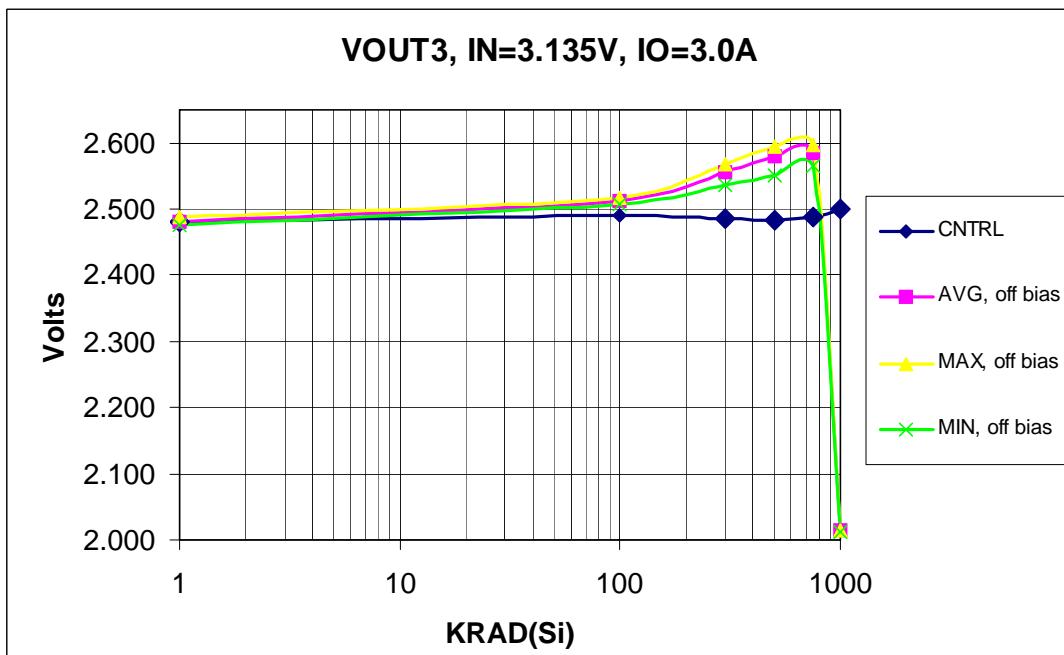


Figure 6 "OFF" Biased Samples, VOUT3

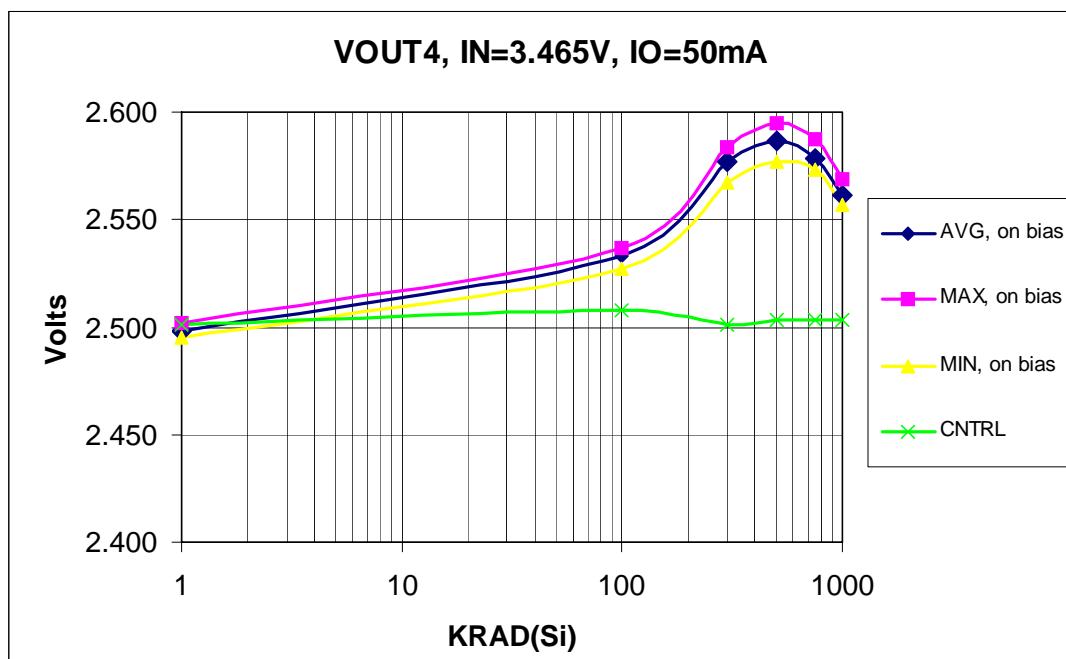


Figure 7 "ON" Biased Samples, VOUT4

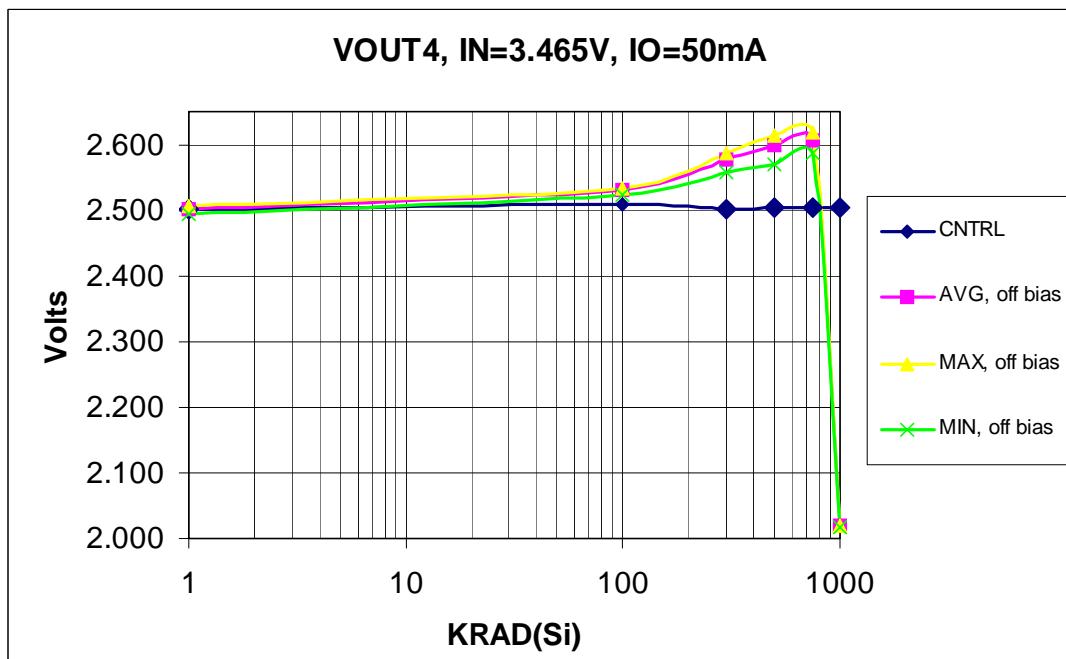


Figure 8 "OFF" Biased Samples, VOUT4

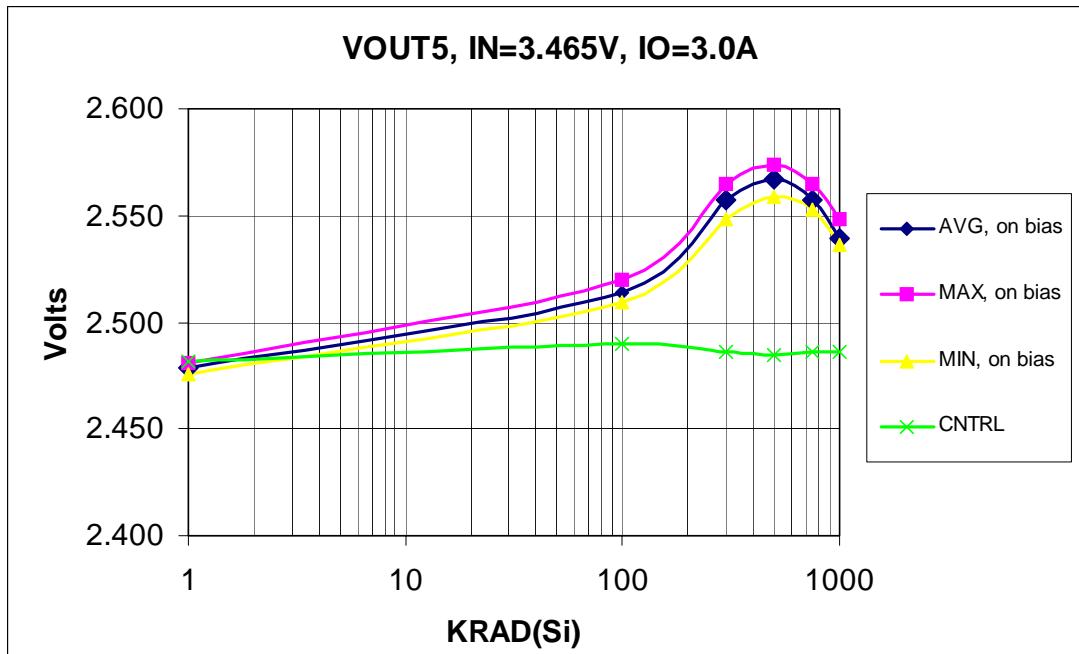


Figure 9 “ON” Biased Samples, VOUT5

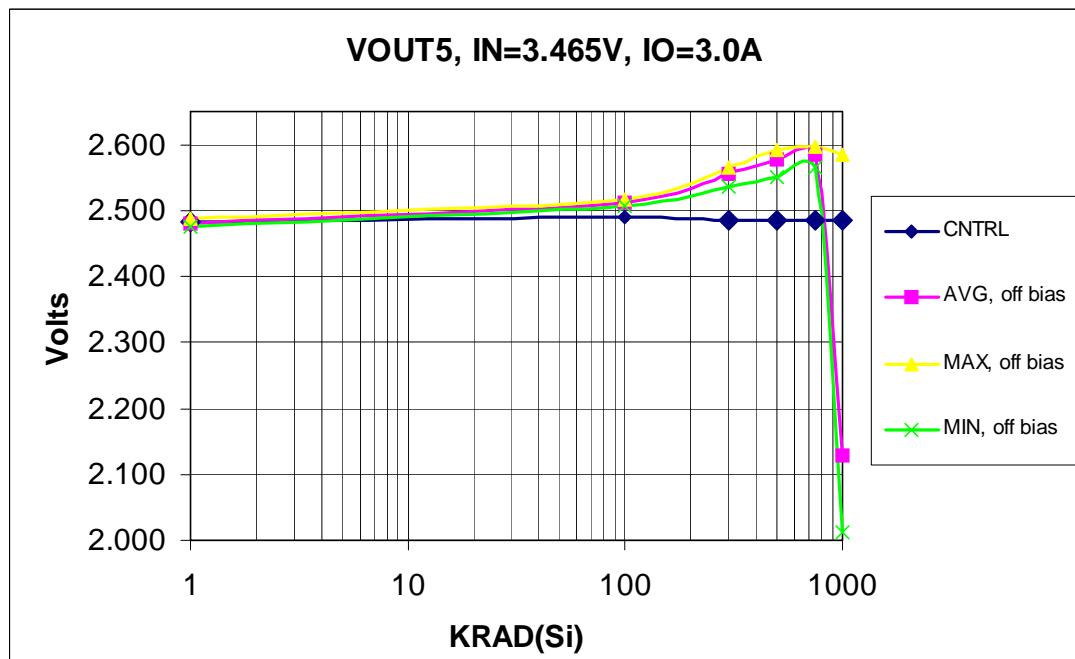


Figure 10 “OFF” Biased Samples, VOUT5

#### Ripple Rejection – Figures 11 and 12

The “ON” bias samples show a downward shift in signal attenuation of 35dB lower at 1M Rad (Si) but the parameter is stable up to 100K Rad (Si). The “OFF” bias samples show a downward shift

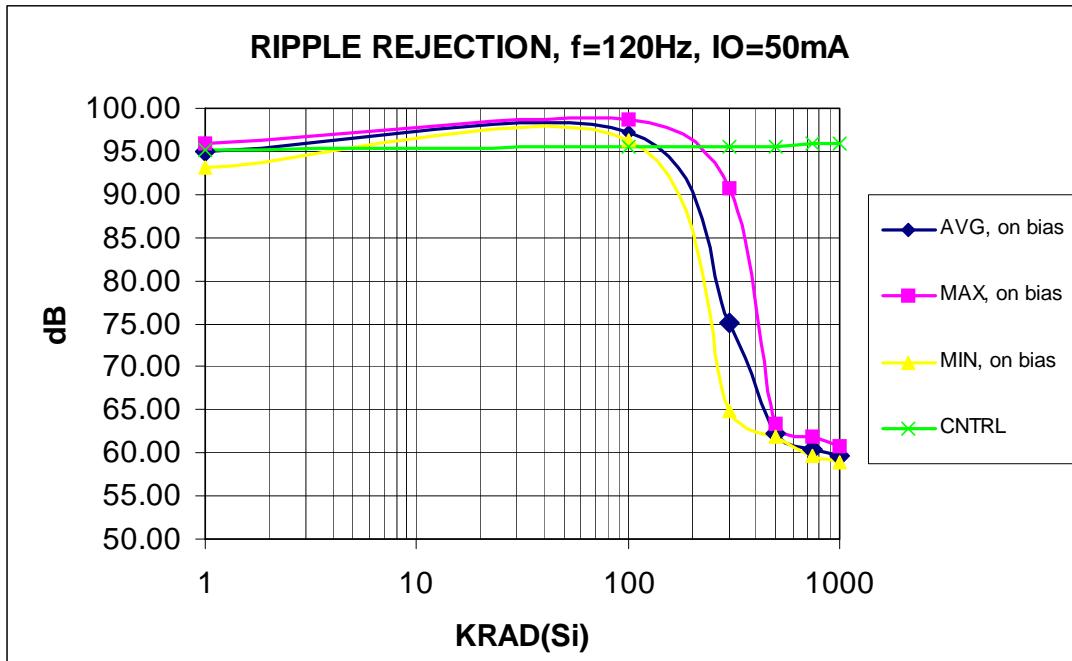


Figure 11 "ON" Biased Samples, RIPPLE REJECTION

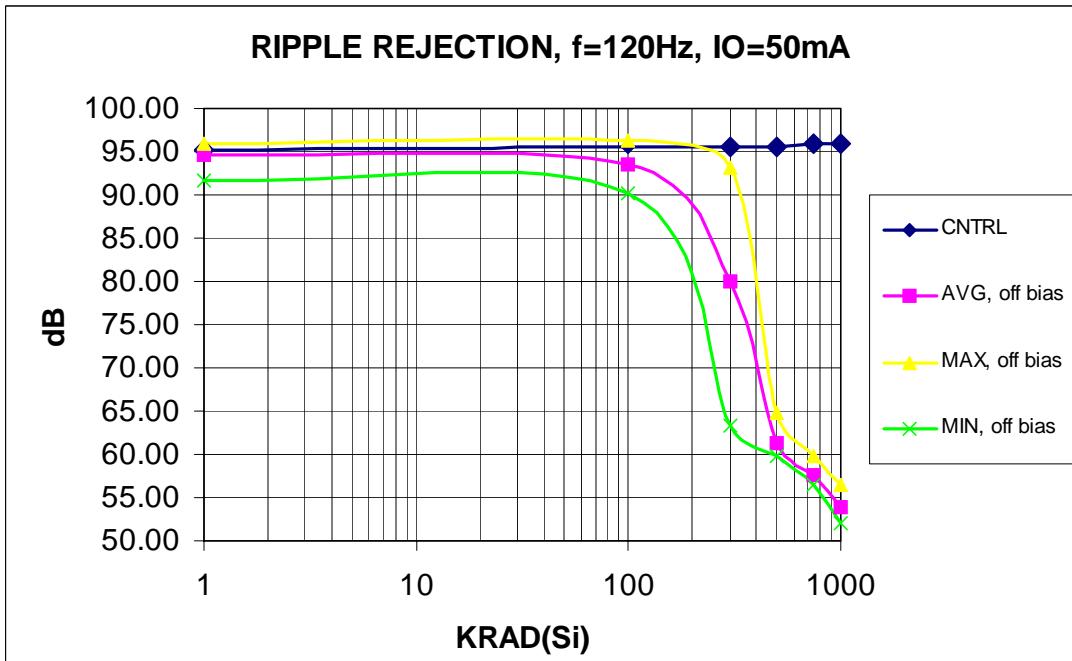


Figure 12 "OFF" Biased Samples, RIPPLE REJECTION

**Shutdown Threshold Voltage – Figures 13 and 14 (not specified over radiation)**

The “ON” bias samples show an overall shift in threshold voltage of +295mV at 500K Rad (Si) but the parameter does start to recover at 1M Rad (Si). The “OFF” bias samples show an overall shift in threshold voltage of +339mV at 1M Rad (Si). Data is shown here on this parameter for information purposes only.

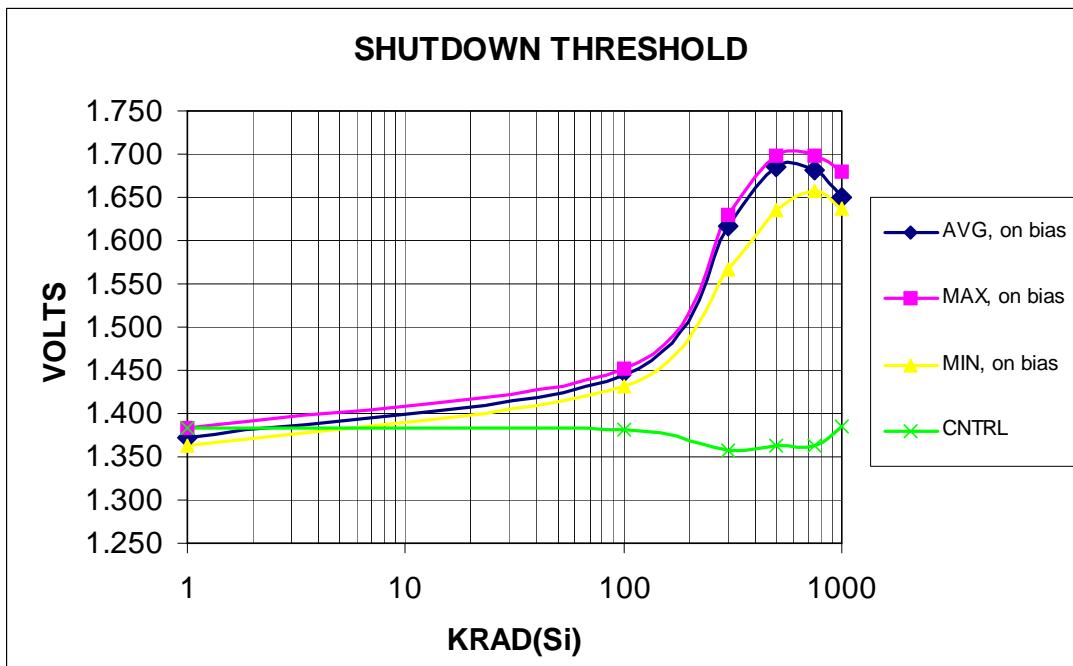


Figure 13 “ON” Biased Samples, SHUTDOWN THRESHOLD

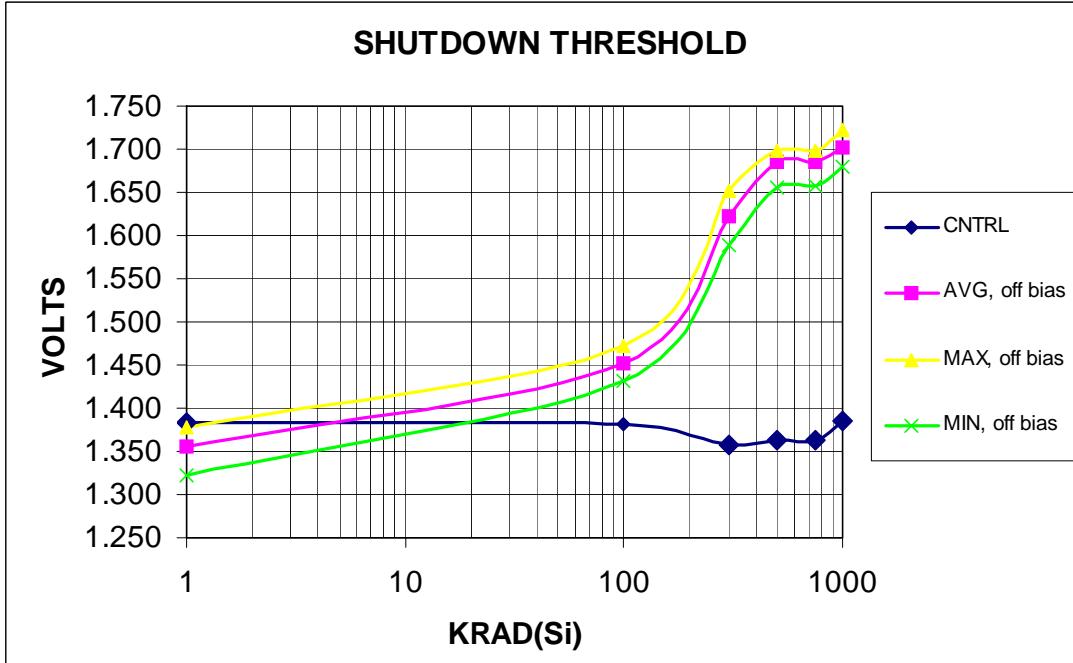


Figure 14 “OFF” Biased Samples, SHUTDOWN THRESHOLD

## **CONCLUSION**

The IRUH33P253B1M has demonstrated hardness to ionizing dose radiation exposure to 1M Rad (Si) with no affect on its performance when the device is in the “ON” bias condition and the results show it to meet all the post radiation test requirements. The results of this testing also show that when this device is in the “OFF” bias condition it meets all post radiation test requirements up to 750K Rad (Si) and can be accepted as a 1M Rad (Si) device based on the results of the extended room temperature anneal per MIL-STD-883, Method 1019. It should also be noted that all of the “OFF” bias samples regulated properly within several seconds after the anneal bias was applied to them.

## Appendix A

## Electrical Data

**Electrical Test Data (Pre-radiation)**

Wednesday, August 24, 2005, 5:42 PM

| TEST      | Vout1 | Vout2 | Vout3 | Vout4 | Vout5 | Vdrop | Ilatch | Ripple Rej | SHDN Thresh | Vout@ SHDN | Ishdn* |
|-----------|-------|-------|-------|-------|-------|-------|--------|------------|-------------|------------|--------|
| Max Limit | 2.525 | 2.625 | 2.625 | 2.625 | 2.625 | 0.400 | ----   | 200        | 1.6         | 100        | ----   |
| Min Limit | 2.475 | 2.375 | 2.375 | 2.375 | 2.375 | ----  | 3      | 65         | 1.0         | -100       | ----   |
| Serial #  | (V)   | (V)   | (V)   | (V)   | (V)   | (V)   | (A)    | (dB)       | (V)         | (mV)       | (uA)   |
| 1703      | 2.494 | 2.504 | 2.48  | 2.501 | 2.482 | 0.209 | 10.13  | 95.16      | 1.384       | -1.18      | 149.58 |
| 1676      | 2.488 | 2.497 | 2.478 | 2.495 | 2.476 | 0.201 | 10.17  | 93.18      | 1.363       | 0.18       | 155.39 |
| 1677      | 2.487 | 2.497 | 2.475 | 2.495 | 2.477 | 0.205 | 10.22  | 95.12      | 1.384       | -2.41      | 152.92 |
| 1678      | 2.489 | 2.497 | 2.479 | 2.498 | 2.478 | 0.209 | 10.22  | 94.81      | 1.363       | -1.32      | 149.11 |
| 1683      | 2.493 | 2.500 | 2.481 | 2.499 | 2.481 | 0.197 | 10.13  | 95.57      | 1.363       | -2.01      | 145.16 |
| 1689      | 2.494 | 2.502 | 2.482 | 2.502 | 2.480 | 0.205 | 9.85   | 95.88      | 1.384       | -2.07      | 147.06 |
| 1693      | 2.489 | 2.497 | 2.476 | 2.497 | 2.476 | 0.197 | 10.58  | 95.12      | 1.322       | -1.68      | 146.25 |
| 1749      | 2.501 | 2.507 | 2.489 | 2.507 | 2.488 | 0.208 | 10.52  | 95.47      | 1.336       | -1.09      | 147.15 |
| 1759      | 2.492 | 2.499 | 2.478 | 2.499 | 2.479 | 0.212 | 10.06  | 91.63      | 1.378       | -1.14      | 158.07 |
| 1762      | 2.498 | 2.506 | 2.486 | 2.505 | 2.485 | 0.197 | 10.56  | 94.79      | 1.378       | -4.94      | 153.07 |
| 1771      | 2.488 | 2.494 | 2.477 | 2.495 | 2.478 | 0.205 | 10.13  | 95.88      | 1.363       | -1.60      | 144.69 |

\* Data collected for information purposes only parameter not specified for pre-radiation.

**Electrical Test Data (Post radiation – 100K Rad (Si))**

Friday, September 02, 2005, 10:06 AM

| TEST      | Vout1 | Vout2 | Vout3 | Vout4 | Vout5 | Vdrop* | Ilatch | Ripple Rej | SHDN Thresh | Vout@ SHDN | Ishdn* |
|-----------|-------|-------|-------|-------|-------|--------|--------|------------|-------------|------------|--------|
| Max Limit | 2.625 | 2.625 | 2.625 | 2.625 | 2.625 | ----   | ----   | 200        | ----        | 100        | ----   |
| Min Limit | 2.375 | 2.375 | 2.375 | 2.375 | 2.375 | ----   | 3      | 40         | ----        | -100       | ----   |
| Serial #  | (V)   | (V)   | (V)   | (V)   | (V)   | (V)    | (A)    | (dB)       | (V)         | (mV)       | (uA)   |
| 1703      | 2.501 | 2.508 | 2.491 | 2.508 | 2.490 | 0.220  | 10.07  | 95.51      | 1.382       | -2.19      | 149.78 |
| 1676      | 2.521 | 2.528 | 2.509 | 2.526 | 2.511 | 0.244  | 9.93   | 92.88      | 1.452       | -1.45      | 148.20 |
| 1677      | 2.523 | 2.531 | 2.512 | 2.532 | 2.512 | 0.233  | 10.11  | 96.26      | 1.452       | -0.19      | 141.49 |
| 1678      | 2.519 | 2.526 | 2.508 | 2.527 | 2.509 | 0.233  | 9.89   | 96.26      | 1.431       | -2.27      | 144.62 |
| 1683      | 2.526 | 2.533 | 2.513 | 2.533 | 2.513 | 0.236  | 10.07  | 96.26      | 1.452       | -0.94      | 137.91 |
| 1689      | 2.531 | 2.537 | 2.519 | 2.537 | 2.520 | 0.244  | 10.02  | 98.18      | 1.452       | -1.15      | 137.80 |
| 1693      | 2.525 | 2.534 | 2.511 | 2.534 | 2.512 | 0.225  | 10.43  | 97.13      | 1.431       | -1.18      | 134.70 |
| 1749      | 2.528 | 2.535 | 2.518 | 2.534 | 2.517 | 0.225  | 10.48  | 93.46      | 1.431       | -1.61      | 140.53 |
| 1759      | 2.518 | 2.525 | 2.507 | 2.524 | 2.507 | 0.233  | 9.98   | 90.24      | 1.473       | -1.14      | 151.57 |
| 1762      | 2.525 | 2.536 | 2.513 | 2.534 | 2.515 | 0.221  | 10.52  | 95.10      | 1.452       | -1.14      | 143.10 |
| 1771      | 2.526 | 2.538 | 2.517 | 2.534 | 2.517 | 0.233  | 10.07  | 98.62      | 1.452       | -0.89      | 134.49 |

\* Data collected for information purposes only parameter not specified for post radiation.

### Electrical Test Data (Post radiation – 300K Rad (Si))

Friday, September 02, 2005, 11:26 AM

| TEST      | Vout1 | Vout2 | Vout3 | Vout4 | Vout5 | Vdrop* | Ilatch | Ripple Rej | SHDN* Thresh | Vout@ SHDN | Ishdn* |
|-----------|-------|-------|-------|-------|-------|--------|--------|------------|--------------|------------|--------|
| Max Limit | 2.625 | 2.625 | 2.625 | 2.625 | 2.625 | ----   | ----   | 200        | ----         | 100        | ----   |
| Min Limit | 2.375 | 2.375 | 2.375 | 2.375 | 2.375 | ----   | 3      | 65         | ----         | -100       | ----   |
| Serial #  | (V)   | (V)   | (V)   | (V)   | (V)   | (V)    | (A)    | (dB)       | (V)          | (mV)       | (uA)   |
| 1703      | 2.500 | 2.506 | 2.486 | 2.501 | 2.486 | 0.225  | 10.16  | 95.52      | 1.358        | -2.43      | 151.68 |
| 1676      | 2.566 | 2.571 | 2.551 | 2.568 | 2.548 | 0.225  | 9.84   | 90.72      | 1.630        | -0.51      | -5.54  |
| 1677      | 2.567 | 2.573 | 2.556 | 2.574 | 2.554 | 0.225  | 9.39   | 90.29      | 1.630        | -1.04      | 133.39 |
| 1678      | 2.558 | 2.567 | 2.546 | 2.567 | 2.548 | 0.228  | 9.57   | 90.72      | 1.567        | -0.74      | 130.28 |
| 1683      | 2.584 | 2.588 | 2.567 | 2.586 | 2.565 | 0.228  | 10.21  | 63.25      | 1.630        | -0.82      | 128.88 |
| 1689      | 2.576 | 2.582 | 2.565 | 2.584 | 2.565 | 0.228  | 10.12  | 64.87      | 1.630        | -0.85      | 127.56 |
| 1693      | 2.570 | 2.579 | 2.557 | 2.577 | 2.557 | 0.217  | 10.57  | 64.92      | 1.630        | -0.45      | 127.47 |
| 1749      | 2.582 | 2.586 | 2.564 | 2.584 | 2.563 | 0.217  | 10.39  | 64.87      | 1.588        | -0.15      | 132.74 |
| 1759      | 2.554 | 2.564 | 2.536 | 2.557 | 2.535 | 0.225  | 9.89   | 93.17      | 1.609        | -1.09      | 144.03 |
| 1762      | 2.584 | 2.586 | 2.565 | 2.585 | 2.564 | 0.217  | 10.52  | 87.64      | 1.651        | -0.43      | 132.23 |
| 1771      | 2.576 | 2.584 | 2.564 | 2.582 | 2.564 | 0.228  | 10.07  | 64.87      | 1.630        | -1.05      | 124.57 |

\* Data collected for information purposes only parameter not specified for pre-radiation.

### Electrical Test Data (Post radiation – 500K Rad (Si))

Friday, September 02, 2005, 12:03 PM

| TEST      | Vout1 | Vout2 | Vout3 | Vout4 | Vout5 | Vdrop* | Ilatch | Ripple Rej | SHDN Thresh | Vout@ SHDN | Ishdn* |
|-----------|-------|-------|-------|-------|-------|--------|--------|------------|-------------|------------|--------|
| Max Limit | 2.625 | 2.625 | 2.625 | 2.625 | 2.625 | ----   | ----   | 200        | ----        | 100        | ----   |
| Min Limit | 2.375 | 2.375 | 2.375 | 2.375 | 2.375 | ----   | 3      | 40         | ----        | -100       | ----   |
| Serial #  | (V)   | (V)   | (V)   | (V)   | (V)   | (V)    | (A)    | (dB)       | (V)         | (mV)       | (uA)   |
| 1703      | 2.500 | 2.505 | 2.484 | 2.503 | 2.485 | 0.218  | 10.167 | 95.49      | 1.363       | -2.79      | 150.08 |
| 1676      | 2.587 | 2.593 | 2.571 | 2.590 | 2.569 | 0.237  | 9.804  | 61.92      | 1.698       | -1.11      | 136.29 |
| 1677      | 2.577 | 2.585 | 2.565 | 2.585 | 2.565 | 0.237  | 9.850  | 61.92      | 1.698       | -1.40      | 130.48 |
| 1678      | 2.569 | 2.577 | 2.559 | 2.577 | 2.559 | 0.241  | 9.804  | 63.34      | 1.635       | -0.61      | 128.25 |
| 1683      | 2.613 | 2.617 | 2.594 | 2.614 | 2.593 | 0.237  | 9.486  | 59.77      | 1.698       | -2.19      | 126.21 |
| 1689      | 2.587 | 2.594 | 2.573 | 2.595 | 2.574 | 0.237  | 9.895  | 61.92      | 1.698       | -0.62      | 1.60   |
| 1693      | 2.580 | 2.588 | 2.566 | 2.588 | 2.567 | 0.229  | 10.213 | 61.92      | 1.698       | -0.95      | 123.56 |
| 1749      | 2.605 | 2.611 | 2.591 | 2.609 | 2.589 | 0.229  | 10.213 | 59.77      | 1.677       | -0.77      | 128.57 |
| 1759      | 2.563 | 2.572 | 2.552 | 2.570 | 2.550 | 0.244  | 9.577  | 64.88      | 1.656       | -0.62      | 139.68 |
| 1762      | 2.606 | 2.612 | 2.590 | 2.610 | 2.587 | 0.222  | 9.850  | 59.73      | 1.698       | -1.53      | 128.40 |
| 1771      | 2.583 | 2.590 | 2.574 | 2.588 | 2.572 | 0.241  | 9.532  | 61.92      | 1.698       | -1.54      | 123.06 |

\* Data collected for information purposes only parameter not specified for post radiation.

### Electrical Test Data (Post radiation – 750K Rad (Si))

Friday, September 02, 2005, 12:41 PM

| TEST      | Vout1 | Vout2 | Vout3 | Vout4 | Vout5 | Vdrop* | Ilatch | Ripple Rej | SHDN* Thresh | Vout@ SHDN | Ishdn* |
|-----------|-------|-------|-------|-------|-------|--------|--------|------------|--------------|------------|--------|
| Max Limit | 2.625 | 2.625 | 2.625 | 2.625 | 2.625 | ----   | ----   | 200        | ----         | 100        | ----   |
| Min Limit | 2.375 | 2.375 | 2.375 | 2.375 | 2.375 | ----   | 3      | 65         | ----         | -100       | ----   |
| Serial #  | (V)   | (V)   | (V)   | (V)   | (V)   | (V)    | (A)    | (dB)       | (V)          | (mV)       | (uA)   |
| 1703      | 2.495 | 2.505 | 2.488 | 2.503 | 2.486 | 0.208  | 10.208 | 95.91      | 1.363        | -2.98      | 153.02 |
| 1676      | 2.595 | 2.603 | 2.578 | 2.600 | 2.576 | 0.245  | 9.345  | 57.23      | 1.698        | 1.12       | 135.69 |
| 1677      | 2.569 | 2.575 | 2.564 | 2.575 | 2.553 | 0.245  | 9.436  | 61.95      | 1.698        | -2.09      | 129.15 |
| 1678      | 2.568 | 2.575 | 2.555 | 2.573 | 2.554 | 0.245  | 9.209  | 60.75      | 1.657        | -0.21      | 127.09 |
| 1683      | 2.609 | 2.619 | 2.596 | 2.619 | 2.597 | 0.245  | 9.890  | 56.58      | 1.678        | -0.30      | 124.12 |
| 1689      | 2.578 | 2.587 | 2.567 | 2.587 | 2.565 | 0.245  | 9.209  | 59.73      | 1.698        | -0.38      | 120.60 |
| 1693      | 2.569 | 2.579 | 2.555 | 2.578 | 2.555 | 0.230  | 10.072 | 59.73      | 1.657        | -0.37      | 120.26 |
| 1749      | 2.606 | 2.617 | 2.597 | 2.615 | 2.595 | 0.241  | 9.572  | 57.94      | 1.657        | 0.12       | 125.55 |
| 1759      | 2.581 | 2.590 | 2.566 | 2.586 | 2.564 | 0.245  | 9.254  | 59.73      | 1.698        | -0.15      | 138.32 |
| 1762      | 2.603 | 2.612 | 2.591 | 2.613 | 2.591 | 0.223  | 10.072 | 56.53      | 1.698        | 1.89       | 130.15 |
| 1771      | 2.572 | 2.580 | 2.561 | 2.578 | 2.559 | 0.245  | 9.527  | 59.77      | 1.698        | -1.03      | 119.68 |

\* Data collected for information purposes only parameter not specified for pre-radiation.

### Electrical Test Data (Post radiation – 1000K Rad (Si))

Friday, September 02, 2005, 1:22 PM

| TEST      | Vout1 | Vout2 | Vout3 | Vout4 | Vout5              | Vdrop* | Ilatch | Ripple Rej | SHDN Thresh | Vout@ SHDN | Ishdn* |
|-----------|-------|-------|-------|-------|--------------------|--------|--------|------------|-------------|------------|--------|
| Max Limit | 2.625 | 2.625 | 2.625 | 2.625 | 2.625              | ----   | ----   | 200        | ----        | 100        | ----   |
| Min Limit | 2.375 | 2.375 | 2.375 | 2.375 | 2.375              | ----   | 3      | 40         | ----        | -100       | ----   |
| Serial #  | (V)   | (V)   | (V)   | (V)   | (V)                | (V)    | (A)    | (dB)       | (V)         | (mV)       | (uA)   |
| 1703      | 2.500 | 2.504 | 2.501 | 2.503 | 2.486              | 0.207  | 9.782  | 95.89      | 1.386       | -2.57      | 152.52 |
| 1676      | 2.016 | 2.018 | 2.013 | 2.018 | 2.013              | 2.352  | 9.146  | 54.27      | 1.700       | -0.46      | 179.94 |
| 1677      | 2.548 | 2.559 | 2.537 | 2.557 | 2.537              | 0.245  | 9.509  | 58.83      | 1.679       | -0.48      | 126.55 |
| 1678      | 2.551 | 2.559 | 2.542 | 2.559 | 2.538              | 0.241  | 8.919  | 60.77      | 1.637       | -0.21      | 125.14 |
| 1683      | 2.016 | 2.018 | 2.013 | 2.018 | 2.013              | 2.340  | 9.419  | 51.99      | 1.679       | -2.25      | 165.87 |
| 1689      | 2.559 | 2.569 | 2.548 | 2.569 | 2.548              | 0.249  | 9.101  | 59.75      | 1.658       | -1.45      | 123.35 |
| 1693      | 2.550 | 2.561 | 2.535 | 2.560 | 2.536              | 0.234  | 9.464  | 59.75      | 1.637       | -0.86      | 120.46 |
| 1749      | 2.015 | 2.019 | 2.014 | 2.019 | 2.015              | 2.343  | 10.024 | 53.31      | 1.702       | -0.81      | 168.40 |
| 1759      | 2.015 | 2.019 | 2.014 | 2.019 | 2.584 <sup>1</sup> | 0.257  | 9.206  | 56.52      | 1.702       | -0.70      | 140.49 |

<sup>1</sup> Device 1759 shows proper regulation for output voltage test five, which is a sign the device has annealed during the test.

|      |       |       |       |       |       |       |       |       |       |       |        |
|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|--------|
| 1762 | 2.015 | 2.019 | 2.014 | 2.019 | 2.015 | 0.238 | 9.524 | 53.66 | 1.723 | -2.58 | 172.41 |
| 1771 | 2.551 | 2.560 | 2.537 | 2.562 | 2.537 | 0.241 | 8.919 | 58.83 | 1.637 | -0.61 | 120.68 |

\* Data collected for information purposes only parameter not specified for post radiation.

### Electrical Test Data (Post 168hr room temperature anneal)\*\*

Friday, September 09, 2005

| TEST      | Vout1 | Vout2 | Vout3 | Vout4 | Vout5 | Vdrop* | Ilatch | Ripple Rej | SHDN Thresh | Vout@ SHDN |
|-----------|-------|-------|-------|-------|-------|--------|--------|------------|-------------|------------|
| Max Limit | 2.625 | 2.625 | 2.625 | 2.625 | 2.625 | ----   | ----   | 200        | ----        | 100        |
| Min Limit | 2.375 | 2.375 | 2.375 | 2.375 | 2.375 | ----   | 3      | 40         | ----        | -100       |
| Serial #  | (V)   | (V)   | (V)   | (V)   | (V)   | (V)    | (A)    | (dB)       | (V)         | (mV)       |
| 1703      | 2.499 | 2.506 | 2.442 | 2.506 | 2.495 | 0.209  | 8.14   | 79.0       | 1.392       | 6.8        |
| 1676      | 2.520 | 2.525 | 2.518 | 2.525 | 2.517 | 0.299  | 6.82   | 79.6       | 1.532       | 5.3        |
| 1677      | 2.517 | 2.523 | 2.514 | 2.523 | 2.513 | 0.283  | 6.94   | 80.4       | 1.548       | 2.9        |
| 1678      | 2.518 | 2.523 | 2.514 | 2.523 | 2.513 | 0.282  | 7.18   | 82.1       | 1.516       | 3.2        |
| 1683      | 2.533 | 2.538 | 2.530 | 2.539 | 2.530 | 0.287  | 6.94   | 80.1       | 1.516       | 4.1        |
| 1689      | 2.523 | 2.529 | 2.519 | 2.529 | 2.519 | 0.287  | 6.94   | 81.3       | 1.528       | 1.7        |
| 1693      | 2.515 | 2.523 | 2.509 | 2.523 | 2.509 | 0.267  | 7.66   | 82.8       | 1.520       | 3.2        |
| 1749      | 2.536 | 2.542 | 2.533 | 2.542 | 2.532 | 0.284  | 7.18   | 79.3       | 1.510       | 0.2        |
| 1759      | 2.516 | 2.522 | 2.513 | 2.522 | 2.512 | 0.294  | 6.82   | 79.8       | 1.540       | 2.4        |
| 1762      | 2.529 | 2.536 | 2.526 | 2.536 | 2.525 | 0.291  | 7.30   | 83.2       | 1.526       | 1.2        |
| 1771      | 2.514 | 2.520 | 2.512 | 2.520 | 2.511 | 0.215  | 7.06   | 83.2       | 1.538       | 0.7        |

\* Data collected for information purposes only parameter not specified for post radiation.

\*\* Tested on the Eagle ETS-564 production test system.

## Appendix B

# Radiation Test Specification

**PRODUCT DESCRIPTION: 2.5V LOW DROPOUT VOLTAGE REGULATOR**

| Automatic Test                               |                  | Tester: PXI TEST CONSOLE 04-134-TC |  |            |       |       |       |       |
|--|------------------|------------------------------------|--|------------|-------|-------|-------|-------|
| Table 1: Pre Radiation Tests, 25C tests only |                  |                                    |  |            |       |       |       |       |
| Prog. Ref.                                   | Test             | Symbol                             | Test Conditions                            | Rad Level: | Notes | MIN   | MAX   | Units |
| A  | Output Voltage   | V out                              | Vin = 3.30 Vdc                             | Pre Rad    |       | 2.475 | 2.525 | Vdc   |
|  |                  |                                    | Iout = 1.5 A                               |            |       |       |       |       |
| A  | Output Voltage   | V out                              | Vin = 3.135 Vdc                            | Pre Rad    |       | 2.375 | 2.625 | Vdc   |
|  |                  |                                    | Iout = 50 mA                               |            |       |       |       |       |
| A  | Output Voltage   | V out                              | Vin = 3.135 Vdc                            | Pre Rad    |       | 2.375 | 2.625 | Vdc   |
|  |                  |                                    | Iout = 3.0 A                               |            |       |       |       |       |
| A  | Output Voltage   | V out                              | Vin = 3.465 Vdc                            | Pre Rad    |       | 2.375 | 2.625 | Vdc   |
|  |                  |                                    | Iout = 50 mA                               |            |       |       |       |       |
| A  | Output Voltage   | V out                              | Vin = 3.465 Vdc                            | Pre Rad    |       | 2.375 | 2.625 | Vdc   |
|  |                  |                                    | Iout = 3.0 A                               |            |       |       |       |       |
| A  | Dropout Voltage  | Vdrop                              | Iout = 3.0 A                               | Pre Rad    |       | 0     | 0.40  | Vdc   |
|  |                  |                                    |  |            |       |       |       |       |
| A  | Current Limit    | I limit                            | Vin = 3.3 Vdc                              | Pre Rad    |       | 3.0   | ---   | A     |
|  |                  |                                    |  |            |       |       |       |       |
| A  | Ripple Rejection | Rrej                               | F= 120 Hz                                  | Pre Rad    |       | 65    | 200   | dB    |
|  |                  |                                    | Iout = 50 mA                               |            |       |       |       |       |
| A  | Shutdown         | Vshutdown                          | Vin = 5.0 Vdc, Vshutdown ramp from 0.8V to | Pre Rad    |       | 1.0   | 1.6   | V     |
|  |                  |                                    | 4.8V, output monitored for 100mV drop      |            |       |       |       |       |
| A  | Output voltage   | Vout shdn                          | Vin = 3.3 Vdc                              | Pre Rad    |       | -0.1  | +0.1  | V     |
|  |                  |                                    | Iout = 50 mA                               |            |       |       |       |       |
|  |                  |                                    | Vshdn = +5 Vdc                             |            |       |       |       |       |
| A  | Shutdown         | Ishutdown                          | Vin = 3.3 Vdc                              | Pre Rad    | 1     | ---   | ---   | uA    |
|  |                  |                                    | Iout = 50 mA                               |            |       |       |       |       |
|  |                  |                                    | Vshdn = +5 Vdc                             |            |       |       |       |       |

Notes:

1. These tests are performed for information purposes only.

This is proprietary information of International Rectifier Hi-Rel Products and it is understood that this will not be divulged to a third party or used in any way prejudicial to the interest of International Rectifier Hi-Rel Products.

| Automatic Test                                |                            | Tester: PXI TEST CONSOLE 04-134-TC |  |            |       |       |       |       |
|---|----------------------------|------------------------------------|--|------------|-------|-------|-------|-------|
| Table 2: Post Radiation Tests, 25C tests only |                            |                                    |  |            |       |       |       |       |
| Prog. Ref.                                    | Test                       | Symbol                             | Test Conditions  | Rad Level: | Notes | MIN   | MAX   | Units |
| B   | Output Voltage             | V out                              | Vin = 3.30 Vdc   | Post Rad   | 1     | 2.375 | 2.625 | Vdc   |
|   |                            |                                    | Iout = 1.5 A   |            |       |       |       |       |
| B   | Output Voltage             | V out                              | Vin = 3.135 Vdc  | Post Rad   | 1     | 2.375 | 2.625 | Vdc   |
|   |                            |                                    | Iout = 50 mA   |            |       |       |       |       |
| B   | Output Voltage             | V out                              | Vin = 3.135 Vdc  | Post Rad   | 1     | 2.375 | 2.625 | Vdc   |
|   |                            |                                    | Iout = 3.0 A   |            |       |       |       |       |
| B   | Output Voltage             | V out                              | Vin = 3.465 Vdc  | Post Rad   | 1     | 2.375 | 2.625 | Vdc   |
|   |                            |                                    | Iout = 50 mA   |            |       |       |       |       |
| B   | Output Voltage             | V out                              | Vin = 3.465 Vdc  | Post Rad   | 1     | 2.375 | 2.625 | Vdc   |
|   |                            |                                    | Iout = 3.0 A   |            |       |       |       |       |
| B   | Dropout Voltage            | Vdrop                              | Iout = 3.0 A   | Post Rad   | 1     | ---   | ---   | Vdc   |
|   |                            |                                    |  |            |       |       |       |       |
| B   | Current Limit              | I limit                            | Vin = 3.3 Vdc  | Post Rad   | 1     | 3.0   | ---   | A     |
|   |                            |                                    |  |            |       |       |       |       |
| B   | Ripple Rejection           | Rrej                               | F= 120 Hz  | Post Rad   | 1     | 40    | 200   | dB    |
|   |                            |                                    | Iout = 50 mA   |            |       |       |       |       |
| B   | Shutdown Threshold         | Vshutdown                          | Vin = 5.0 Vdc, Vshutdown ramp from 0.8V to 4.8V, output monitored for 100mV drop | Post Rad   | 1     | ---   | ---   | V     |
|   |                            |                                    |  |            |       |       |       |       |
| B   | Output voltage At Shutdown | Vout shdn                          | Vin = 3.3 Vdc  | Post Rad   | 1     | -0.1  | +0.1  | V     |
|   |                            |                                    | Iout = 50 mA   |            |       |       |       |       |
| B   | Shutdown Pin Current       | Ishutdown                          | Vshdn = +5 Vdc   | Post Rad   | 1     | ---   | ---   | uA    |
|   |                            |                                    |  |            |       |       |       |       |
| B   | Shutdown Pin Current       | Ishutdown                          | Vin = 3.3 Vdc  | Post Rad   | 1     | ---   | ---   | uA    |
|   |                            |                                    | Iout = 50 mA   |            |       |       |       |       |
|   |                            |                                    | Vshdn = +5 Vdc   |            |       |       |       |       |

Notes:

- These tests are performed for information purposes only.

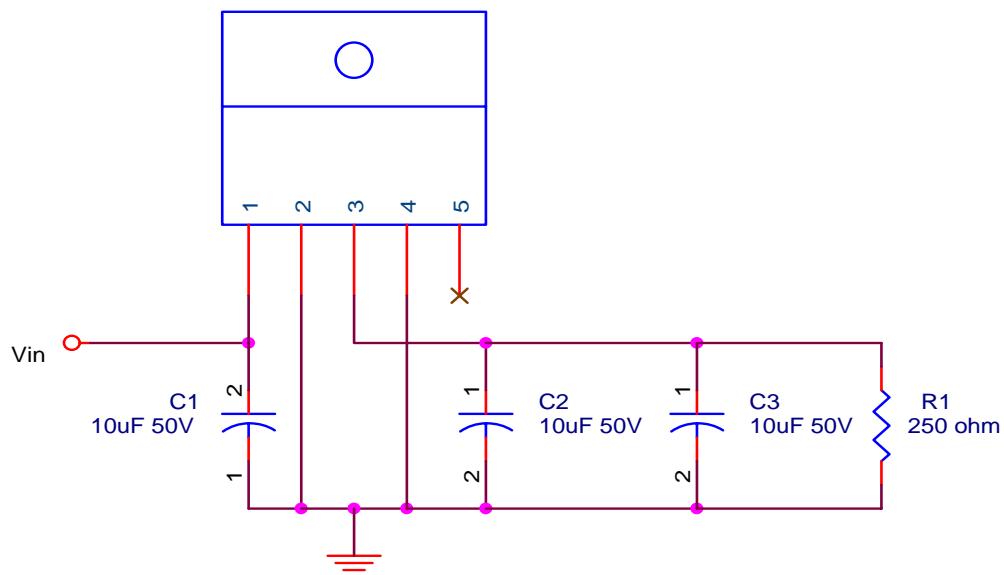
This is proprietary information of International Rectifier Hi-Rel Products and it is understood that this will not be divulged to a third party or used in any way prejudicial to the interest of International Rectifier Hi-Rel Products.

**Table 3: Total Dose Radiation Requirements**

| High Dose Rate <sup>2</sup> |                                  |  |
|-----------------------------|----------------------------------|--|
| Bias Conditions             | Vin = 6.8V, Vout = 2.5V, Io=10mA | Unbiased, in circuit with power supply off |
| Dose Step Profile           | 100K, 200K, 200K, 250K, 250K     | 100K, 200K, 200K, 250K, 250K               |
| Dose Rate Range             | 50 to 300 Rad(Si)/sec            | 50 to 300 Rad(Si)/sec                      |
| Board Number                | TF-02-011                        | TF-02-011                                  |
| Program Card Number         | TA-02-001                        | TA-02-001                                  |
| Chamber                     | Gamma Cave                       | Gamma Cave                                 |
| Test Temperature            | 25C +/-5C                        | 25C +/-5C                                  |

2. Performed at during initial qualification of the device and retested only when specified by Quality Assurance due to a change per MIL-PRF-38534.

**Radiation Circuit**

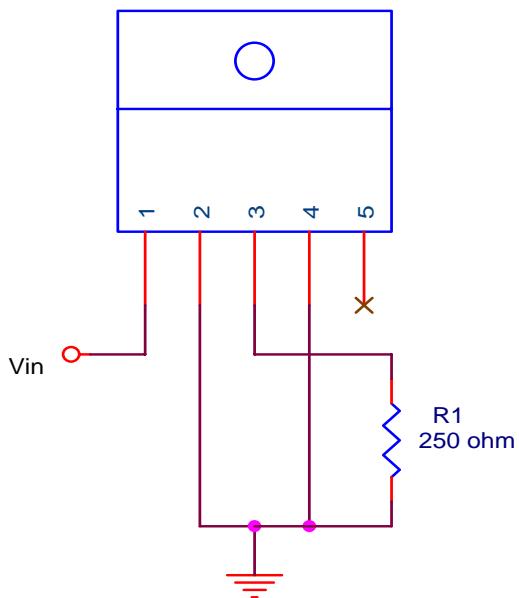


| Table 4: Anneal Test Requirements             |                                    |
|---|------------------------------------|
| Extended Room Temperature Anneal <sup>3</sup> |                                    |
| Bias Conditions                               | Vin = 6.8V, Vout = 2.5V, Io = 10mA |
| Chamber Temperature                           | 24C +6C, -6C                       |
| Duration                                      | 168hrs +/- 12hrs                   |
| Burn-in Board                                 | BB037                              |
| Program Card Number                           | BP0539                             |

3. The extended room temperature anneal is performed on devices that fail to meet the 1000K dose rating. If the devices pass the post-irradiation testing after this extended room temperature anneal then they shall be considered qualified product.. This test does not apply to products tested at Low Dose rate.

Anneal Test Circuit

Pinout  
 1 - Input  
 2 - Gnd  
 3 - Output  
 4 - Shutdown  
 5 - N/C



| Table 7: Test Hardware |                          |               |
|------------------------|--------------------------|---------------|
|                        | Test Fixture             | Test System   |
| Pre Radiation Tests    | 04-135-TF, 04-135-010-TA | PXI 04-134-TC |
| Post Radiation Tests   | 04-135-TF, 04-135-010-TA | PXI 04-134-TC |